

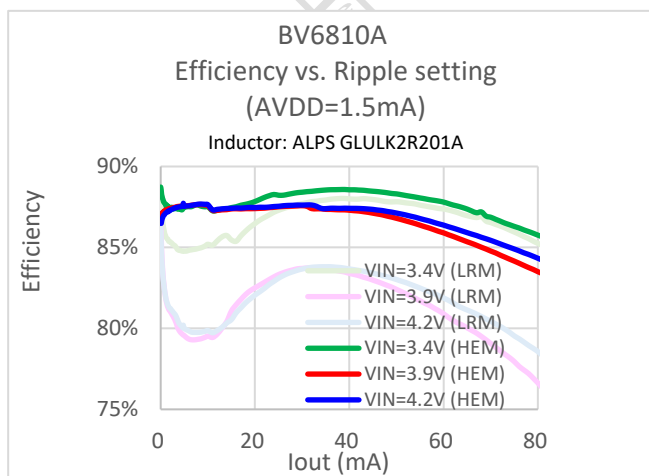
AMOLED Power Solution

1 General Description

The BV6810A is a highly integrated power solution for AMOLED Display application, which uses a single-inductor-tripolar-output (SITO) converter to generate two positive and one negative voltage outputs. It does not need an extra charge pump circuit to generate the negative voltage output so that external capacitors required by the charge pump circuit can be eliminated and the PCB space can be achieved with very small.

The output voltages can be adjusted by SWIRE pin. Compared with the scheme of generating negative voltage by a charge pump circuit, the best energy conversion efficiency can only be obtained near the negative voltage ratio provided by its charge pump circuit. This SITO architecture can provide a stable high conversion efficiency throughout the entire negative voltage adjusting range. Therefore, this solution can provide the optimal negative voltage output value according to different brightness requirements to reduce the power consumption of the AMOLED display significantly. This is the best solution that can optimize the solution form factor as well as display power consumption.

With its input voltage range from 2.9V to 5.5V, BV6810A is optimized for products powered by single-cell batteries with output currents up to 80mA. The BV6810A is available in the WL-CSP-12B 1.39mm x 1.64mm package.



2 Features

- Input Voltage Range: 2.9V to 5.5V
- Positive Output Voltage AVDD Range: 2.8V to 3.7V
(SET=Floating Default is 2.8V±1%)
(SET=High/Low Default is 3.3V±1%)
- Positive Output Voltage OVDD Range: 2.6V to 5.3V
(SET=High/Floating Default is 4.6V±1%)
(SET=Low Default is 3.3V±1%)
- Negative Output Voltage OVSS Range: -0.6V to -4.7V
(SET=High/Floating Default is -2.4V±1%)
(SET=Low Default is -3.3V±1%)
- Low Quiescent Current: 25μA
- AVDD Max. Loading is 10mA, OVDD and OVSS Max. loading is 80mA.
- Built-in Internal Soft start
- UVLO, UVP, SCP, OCP, OTP, and SSP protection

3 Applications

- Wearable AMOLED Product

4 Ordering Information

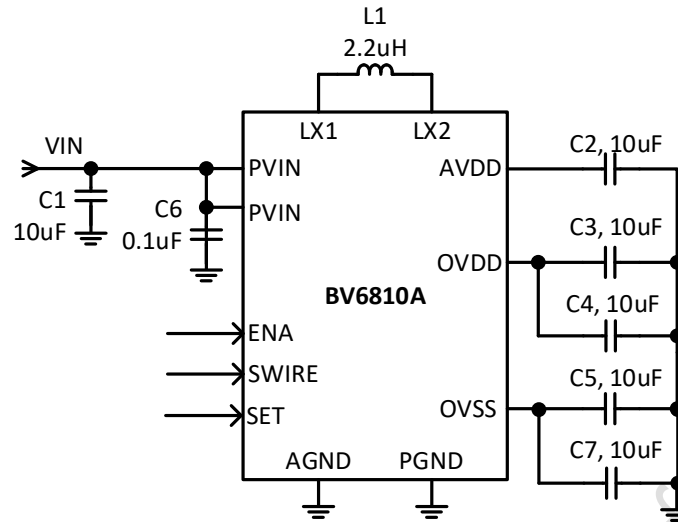
Part Number	Package	Body Size
BV6810A	WLCSP (12)	1.39mmx1.64mm

(1) For all available package, see the orderable addendum at the end of the datasheet.

Note:

Bravotek products are RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020Package Information.

5 Application Circuit



Note: AVDD=3.3V, OVDD=3.3V, OVSS=-3.3V when SET pull Low after power on

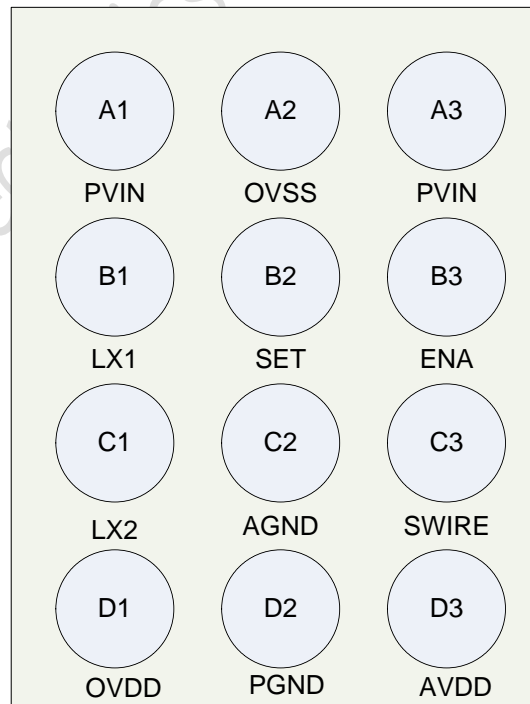
AVDD=3.3V, OVDD=4.6V, OVSS=-2.4V when SET pull High after power on

AVDD=2.8V, OVDD=4.6V, OVSS=-2.4V when SET is floating after power on

The SET pull-high/low resistor must have a resistance of 0 ohm

6 Pin Configuration and Function

BV6810A



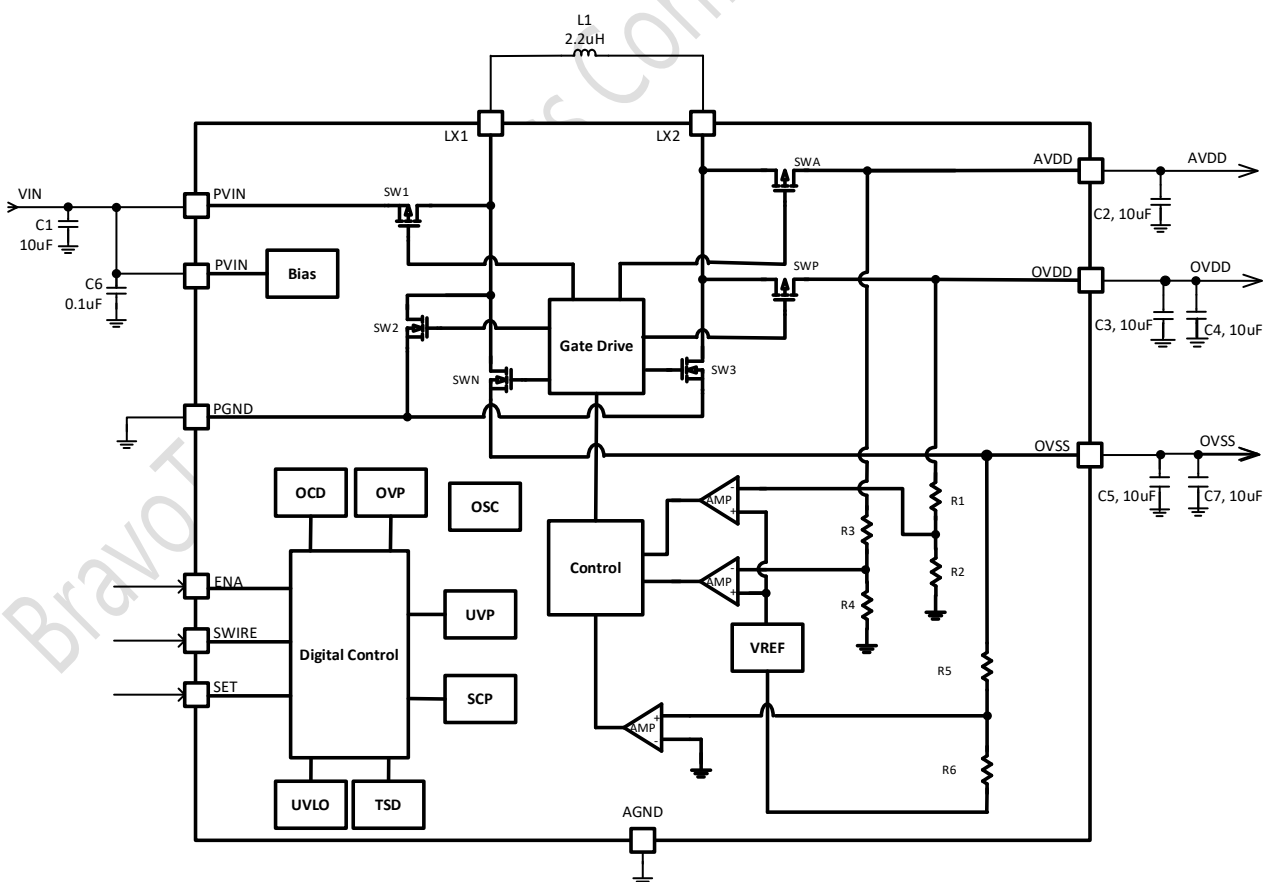
Top View

Pin	Name	Function
A1	PVIN	Power Input for SITO
A2	OVSS	OVSS Output
A3	PVIN	Power Input for SITO
B1	LX1	LX1 switching node for SITO
B2	SET	The Pin for Setting default voltage
B3	ENA	Enable for IC and AVDD
C1	LX2	LX2 switching node for SITO
C2	AGND	Analog Ground
C3	SWIRE	SWIRE Control Interface
D1	OVDD	OVDD Output
D2	PGND	Power Ground
D3	AVDD	AVDD Output

7 Device Comparable Table

Device Option	Package	Rated Current	Output Voltage
BV6810AW	WLCSP-12B 1.39mm x 1.64mm	OVDD, OVSS: 80mA AVDD: 10mA	Set by SWIRE

8 Functional Block Diagram



9 Absolute Maximum Ratings

- Supply Input Voltage: PVIN to ANGND, PGND -0.3V to 6.0V
- AVDD, OVDD, SWIRE, ENA, SET to AGND, PGND -0.3V to 6.0V
- OVSS to AGND, PGND -6.0V to 0.3V
- Power Dissipation, PD@ TA=25°C
 WL-CSP-12B 1.42W
- Package Thermal Resistance
 WL-CSP-12B, θ_{JA} 80.84°C/W
 WL-CSP-12B, θ_{JC} 4.5°C/W
- Lead Temperature (Soldering, 10sec.) 260°C
- Junction Temperature 150°C
- Storage Temperature -65°C to 150°C
- ESD Susceptibility
 HBM (Human Body Model) 2KV
 CDM (Machine Model) 500V

10 Recommended Operating Conditions

- Supply Input Voltage 2.9V to 5.5V
- Junction Temperature Range -40°C to 125°C
- Ambient Temperature Range -40°C to 85°C

Note:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The device is not guaranteed to function outside its recommended operating conditions.

11 Components Selection

11.1 Inductor

Reference	Value	Component supplier	Package	Isat / DCR
L1	2.2uH	ALPS GLULK2R201A	2.5mm x 2.0mm x 1.0mm	1.8A / 85mΩ
L1	2.2uH	Cyntec HTQA20161T-2R2MSRG	2.0mm x 1.6mm x 1.0mm	2.6A / 100mΩ

11.2 Capacitors

Reference	Value	Component supplier	Package
C1, C2, C5, C7 ^(*2) C3, C4	10uF/6.3V	GRM155R60J106ME15D	0402
C6	0.1uF/6.3V	GRM033R60J104KE19D	0201
C3 ^(*1) , C4 ^(*1)	22uF/6.3V	GRM158R60J226ME01D	0402
C3 ^(*1) C4 ^(*1) : 10uF capacitance is also recommended for C3 and C4, depending on visual performance. C7 ^(*2) : Removing C7 is also recommended, depending on visual performance.			

12 Electrical Characteristics

$V_{IN}=3.7V$, $AVDD=2.8V$, $OVDD=4.6V$, $OVSS=-2.4V$, $T_A=25^{\circ}C$, unless otherwise specified.						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input Power Supply						
Input Supply Voltage	V_{IN}		2.9	3.7	5.5	V
Quiescent Current	I_Q	SWIRE=High, AVDD_EN=High, measured into VIN pin. No load	-	25	-	μA
Idle Current	I_{IDLE}	AVDD_EN =High and SWIRE =Low	-	14	-	μA
Shutdown Current	I_{SHDN}	AVDD_EN and SWIRE = Low	-	0.2	1	μA
Under-Voltage Lockout Threshold	V_{UVLOH}	VIN Rising	-	2.4	2.5	V
	V_{UVLOL}	VIN falling	-	2.25	2.35	V
Thermal Shutdown	T_{SD}		-	140	-	$^{\circ}C$
Thermal Shutdown Hysteresis	ΔT_{SD}		-	10	-	$^{\circ}C$
SWIRE						
SWIRE Logical High-Level Voltage	V_{SRH}	$V_{IN}=2.9V$ to $5.5V$	1.2	-	-	V
SWIRE Logic Low-Level Voltage	V_{SRL}	$V_{IN}=2.9V$ to $5.5V$	0	-	0.4	V
SWIRE Turn-off Detection	T_{OFF_DLY}		-	-	300	μs
SWIRE Signal Stop Indicate Time	T_{STOP}		-	-	300	μs
SWIRE Rising Time	T_r		-	-	200	ns
SWIRE Falling Time	T_f		-	-	200	ns
Clocked SWIRE High	T_{ON}		2	5	20	μs
Clocked SWIRE Low	T_{OFF}		2	5	20	μs
Input Clocked SWIRE Frequency	F_{SWIRE}		25	-	250	KHz
ENA						
AVDD Enable Input Voltage	V_{IH}	$V_{IN}=2.9V$ to $5.5V$	1.2	-	-	V
	V_{IL}	$V_{IN}=2.9V$ to $5.5V$	0	-	0.4	V
SITO						
Over Current Protection	I_{OCP}		0.75	0.9	1.15	A
AVDD						
Positive Output Voltage Range	V_{AVDD_RANGE}	SET=High/Low	2.8	3.3	3.7	V
		SET=Floating	2.8	2.8	3.7	V
Positive Output Voltage Accuracy	V_{AVDD_ACC}		-1	-	1	%
Output Current Capability	I_{AVDD}		-	-	10	mA
Line Regulation	V_{AVDD_LINE}	$V_{IN}=2.9$ to $5.5V$, $I_{AVDD}=1.5mA$	-	3	5	mV
Load Regulation	V_{AVDD_LOAD}	$I_{AVDD} = 0$ to $10mA$	-	-	5	mV

Output Ripple	V _{AVDD_RIPPLE}	I _{AVDD} = 1.5mA	-	-	15	mV
Current Limit	I _{AVDD_LIMIT}		-	20	-	mA
Discharge Resistance	R _{AVDD_RDIS}		-	100	-	Ω
Under Voltage Protection			75	80	85	%
UVP Detection Time			0.4	0.5	0.5	ms
Short Circuit Protection	V _{AVDD_SCP}		-	50	-	%
OVDD						
Positive Output Voltage Range	V _{OVDD_RANGE}	SET=High/Floating	2.6	4.6	5.3	V
		SET=Low	2.6	3.3	5.3	V
Positive Output Voltage Accuracy	V _{OVDD_ACC}		-1	-	1	%
Output Current Capability	I _{OVDD}		-	-	80	mA
Line Regulation	V _{OVDD_LINE}	V _{IN} =2.9 to 5.5V, I _{OVDD} =1mA	-	4	5	mV
Load Regulation	V _{OVDD_LOAD}	I _{OVDD} = 0 to 30mA	-	-	5	mV
Output Ripple	V _{OVDD_RIPPLE}	I _{OVDD} = 10mA	-	-	10	mV
Discharge Resistance	R _{OVDD_RDIS}		-	100	-	Ω
Under Voltage Protection			85	90	95	%
UVP Detection Time			0.4	0.5	0.5	ms
Short Circuit Protection	V _{OVDD_SCP}		-	50	-	%
OVSS						
Negative Output Voltage Range	V _{OVSS_RANGE}	SET=High/Floating	-4.7	-2.4	-0.6	V
		SET=Low	-4.7	-3.3	-0.6	V
Negative Output Voltage Accuracy	V _{OVSS_ACC}		-1	-	1	%
Output Current Capability	I _{OVSS}		-	-	80	mA
Line Regulation	V _{OVSS_LINE}	V _{IN} =2.9 to 5.5V, I _{OVSS} =1mA	-	4	5	mV
Load Regulation	V _{OVSS_LOAD}	I _{OVSS} = 0 to 30mA	-	-	7	mV
Output Ripple	V _{OVSS_RIPPLE}	I _{OVSS} = 10mA	-	-	15	mV
Discharge Resistance	R _{OVSS_RDIS}		-	100	-	Ω
Under Voltage Protection			75	80	85	%
UVP Detection Time			0.4	0.5	0.5	ms
Short Circuit Protection	V _{OVSS_SCP}		-	50	-	%

13 Detail Descriptions

The BV6810A operates with a six-switch buck-boost converter topology to generation a negative and two positive output voltages with a single inductor. The IC have the best efficiency over the entire load-current range. It is implemented by reducing the converter switching frequency into the PSM mode for light load. The output voltage can be set by SWIRE pin, OVSS voltage is from -0.6V to -4.7V. BV6810A can supply the maximum output current up to 80mA for high luminance application.

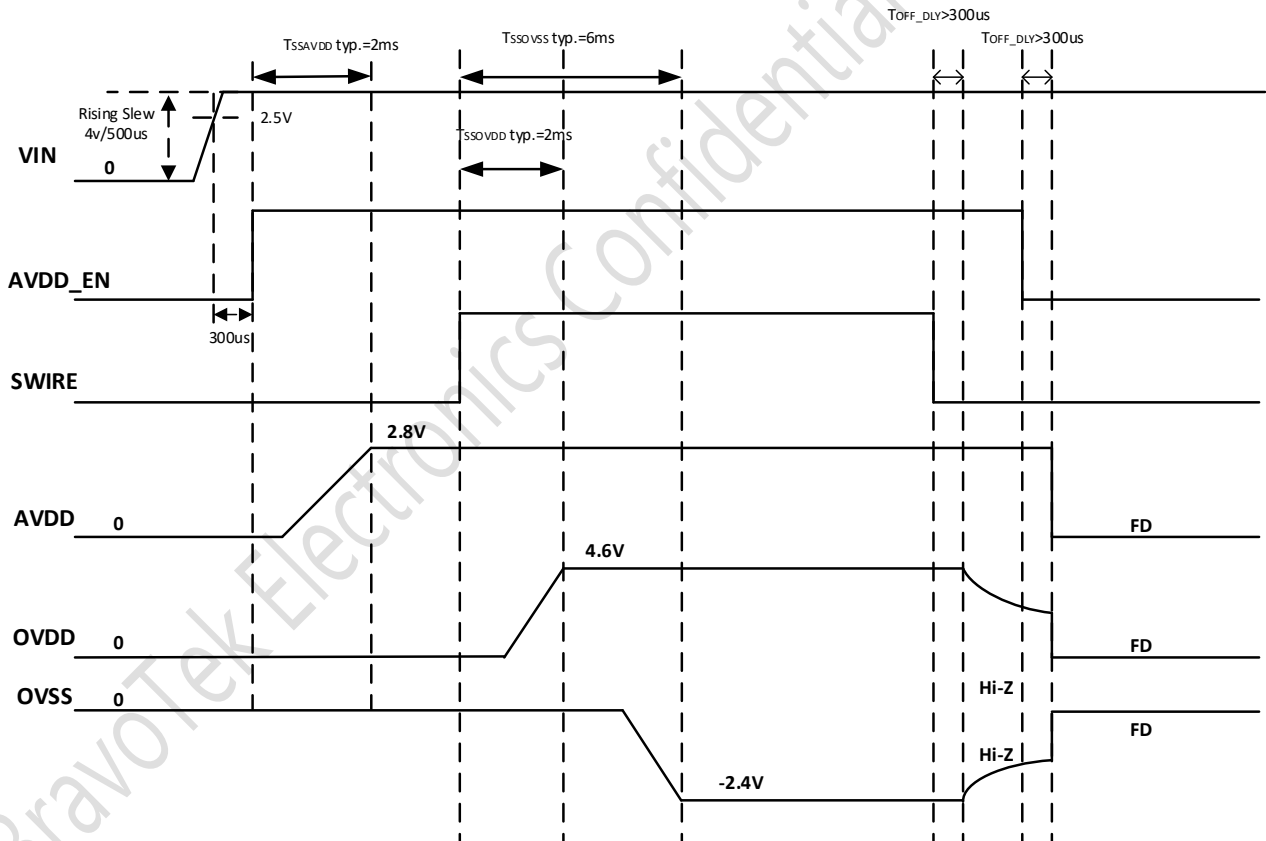
The BV6810A provides the Under-Voltage Protection (UVP), Short-Circuit Protection (SCP), Over-Temperature Protection (OTP) and Over-Current Protection (OCP).

13.1 Power Sequence

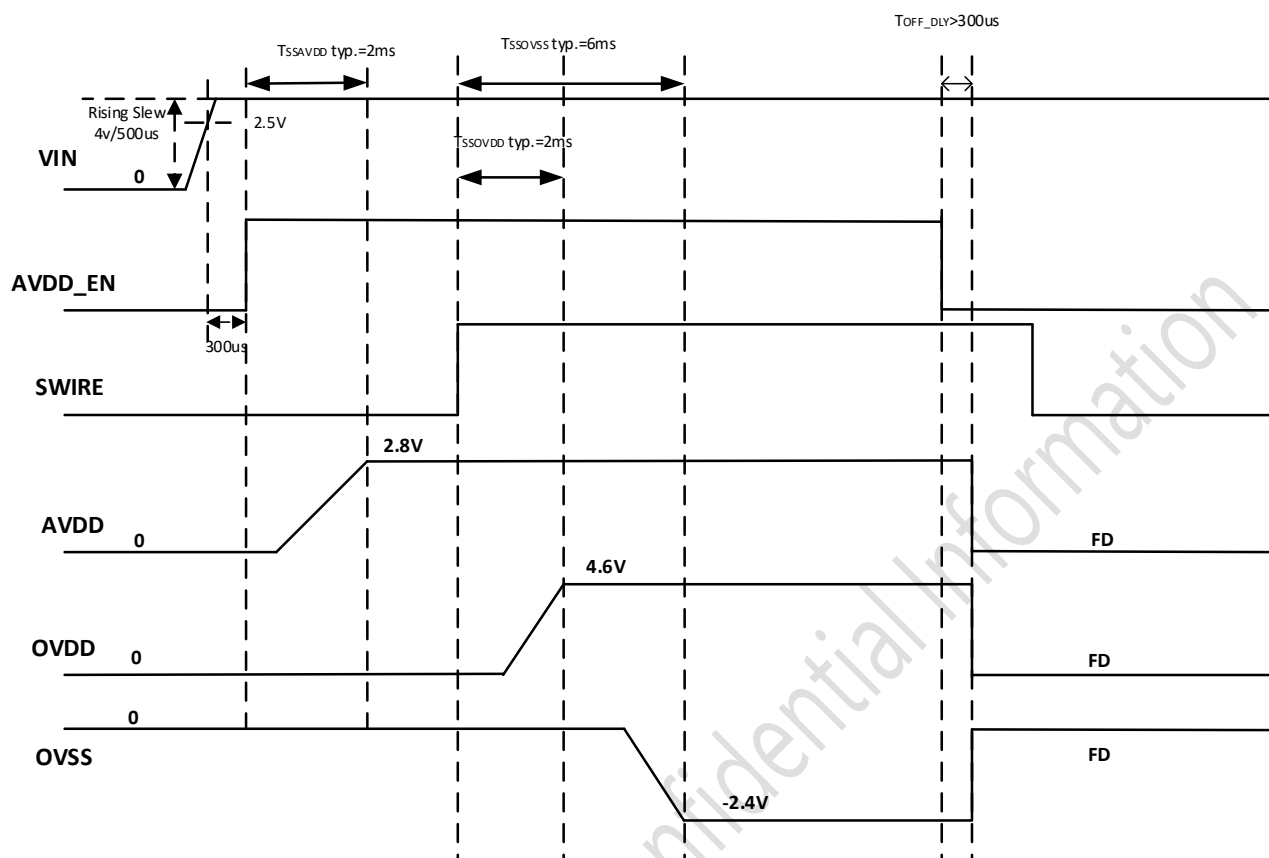
Note:

VIN rising time is not recommended if faster than 100us/4V

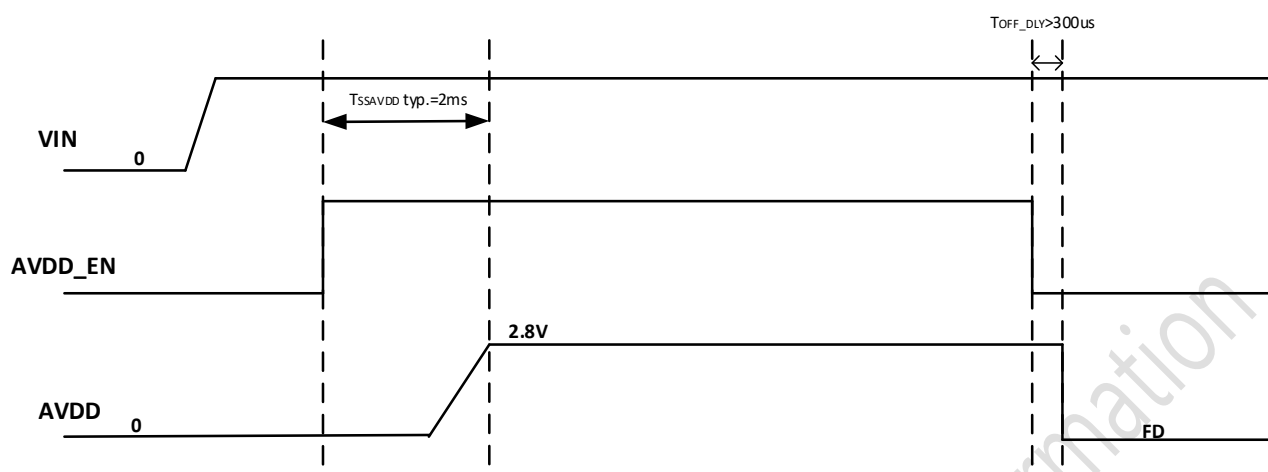
13.1.1 ENA = ON ➡ SWIRE=ON ➡ SWIRE=OFF ➡ ENA=OFF



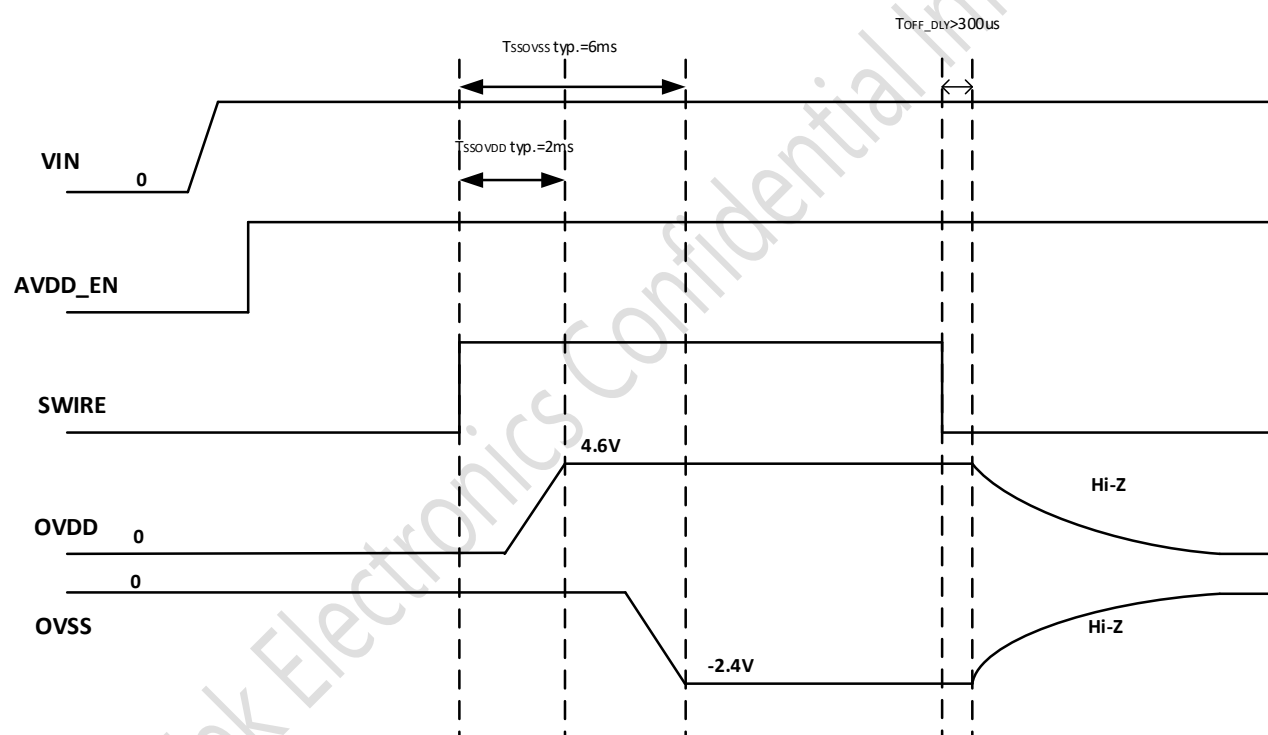
13.1.2 ENA = ON ➔ SWIRE=ON ➔ ENA=OFF ➔ SWIRE=OFF



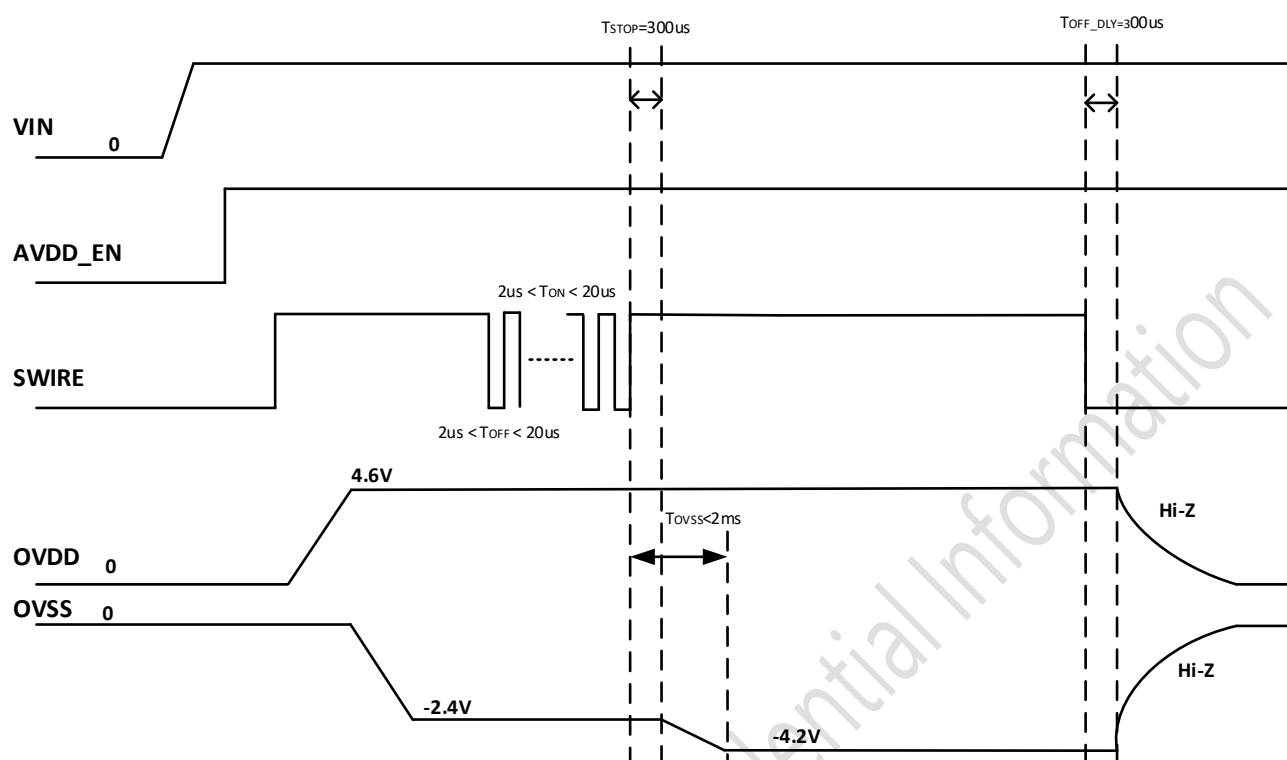
13.1.3 ENA Power ON-OFF Sequence



13.1.4 SWIRE Power ON-OFF Sequence



13.1.5 OVSS Voltage setting by SWIRE



13.2 Protection Functions

13.2.1 Under-Voltage Protection

All outputs are protected against short circuits either to GND. The IC will go into shutdown mode when the output voltage is under the limit level (OVDD=90%, AVDD/OVSS=80% and keep 0.5ms). The IC can only restart normal operation after re-power on.

13.2.2 Over-Temperature Protection

The BV6810A include an over temperature protection circuit to prevent overheating. The IC will disable positive and negative output when the junction temperature exceeds 140°C. Once the junction temperature drops down 10°C approximately, IC will automatically recovery into normal operation.

13.2.3 Short-Circuit Protection

All outputs are protected against short circuits either to GND. The IC will go into shutdown mode immediately when the output short to ground, and the output voltage is under the limit level (50%). The IC can only restart normal operation after re-power on.

13.2.4 Over-Current Protection

The BV6810A includes a cycle-by-cycle current limit function which monitor the inductor current during Phase 1 period. The power switch will be forced off to avoid large current damage IC when the current is over the limit level (0.9A).

13.3 SWIRE Setting

Pulse	Function Description
150	AVDD, OVDD, OVSS setting switch to table II
151	AVDD, OVDD, OVSS setting switch to table I (Default)

Table I

Pulse	Function Description
3-5	LX Slew rate Control
10-13	OVSS transient time method
14-17	VRC function
18-19	Ring-Killer function
22-31	AVDD setting (2.8V to 3.7V)
36-63	OVDD setting (2.6V to 5.3V)
70-111	OVSS setting (-4.7V to -0.6V)
118-119	Sleep Mode
124	OVDD and OVSS fast discharge when SWIRE pull low
125	OVDD and OVSS Hi-Z when SWIRE pull low
128	OVDD turn off (Hi-Z)
129	OVSS turn off (Hi-Z)
130	OVSS discharge to GND
131	Soft-Reset, clear above settings to default code (OVSS voltage setting doesn't)

3~5 Pulse – LX Slew rate Control

Pulse	Description
3	1nS
4	3nS
5	5nS

10, 13 Pulse – OVSS transient time method

Pulse	Description
10	Direct change (40uS/0.1V)
13	Smoothly change within 16mS

14~17 Pulse – VRC (VOUT Ripple Control) function

Pulse	Description
14	Low Ripple Mode (LRM)
15	High Efficiency Mode (HEM)
16	Middle Ripple Mode (MRM)
17	Middle Efficiency Mode (MEM)

18~19 Pulse – Ring-Killer function

Pulse	Description
18	On
19	Off

118~119 Pulse – Sleep Mode function

Pulse	Description
118	Off
119	ON

124 and 125 Pulse – Discharge function

Default (125 Pulse)				
AVDD_EN	SWIRE	AVDD	OVDD	OVSS
0	0	FD	FD	FD
0	1	FD	FD	FD
1	0		Hi-Z	Hi-Z

124 Pulse				
AVDD_EN	SWIRE	AVDD	OVDD	OVSS
0	0	FD	FD	FD
0	1	FD	FD	FD
1	0		FD	FD

Pulse	AVDD
22	2.8V
23	2.9V
24	3.0V
25	3.1V
26	3.2V
27	3.3V
28	3.4V
29	3.5V
30	3.6V
31	3.7V

Pulse	OVDD
36	2.6V
37	2.7V
38	2.8V
39	2.9V
40	3.0V
41	3.1V
42	3.2V
43	3.3V
44	3.4V
45	3.5V
46	3.6V
47	3.7V
48	3.8V
49	3.9V
50	4.0V
51	4.1V
52	4.2V
53	4.3V
54	4.4V
55	4.5V
56	4.6V
57	4.7V
58	4.8V
59	4.9V
60	5.0V
61	5.1V
62	5.2V
63	5.3V

Pulse	OVSS	Pulse	OVSS
70	-4.7V	91	-2.6V
71	-4.6V	92	-2.5V
72	-4.5V	93	-2.4V
73	-4.4V	94	-2.3V
74	-4.3V	95	-2.2V
75	-4.2V	96	-2.1V
76	-4.1V	97	-2.0V
77	-4.0V	98	-1.9V
78	-3.9V	99	-1.8V
79	-3.8V	100	-1.7V
80	-3.7V	101	-1.6V
81	-3.6V	102	-1.5V
82	-3.5V	103	-1.4V
83	-3.4V	104	-1.3V
84	-3.3V	105	-1.2V
85	-3.2V	106	-1.1V
86	-3.1V	107	-1.0V
87	-3.0V	108	-0.9V
88	-2.9V	109	-0.8V
89	-2.8V	110	-0.7V
90	-2.7V	111	-0.6V

Table II

Pulse	Function Description
3-5	LX Slew rate Control
10-13	OVSS transient time method
14-17	VRC function
18-19	Ring-Killer function
20-61	OVSS setting (-4.7V to -0.6V)
70-79	AVDD setting (2.6V to 3.5V)
80-107	OVDD setting (2.6V to 5.3V)
118-119	Sleep Mode
124	OVDD and OVSS fast discharge when SWIRE pull low
125	OVDD and OVSS Hi-Z when SWIRE pull low
128	OVDD turn off (Hi-Z)
129	OVSS turn off (Hi-Z)
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131	Soft-Reset, clear above settings to default code (OVSS voltage setting doesn't)

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17	Middle Efficiency Mode (MEM)

18~19 Pulse – Ring-Killer function

Pulse	Description
18	On
19	Off

118~119 Pulse – Sleep Mode function

Pulse	Description
118	Off
119	ON

124 and 125 Pulse – Discharge function

Default (125 Pulse)				
AVDD_EN	SWIRE	AVDD	OVDD	OVSS
0	0	FD	FD	FD
0	1	FD	FD	FD
1	0		Hi-Z	Hi-Z

124 Pulse				
AVDD_EN	SWIRE	AVDD	OVDD	OVSS
0	0	FD	FD	FD
0	1	FD	FD	FD
1	0		FD	FD

Vout Pulse - Voltage function

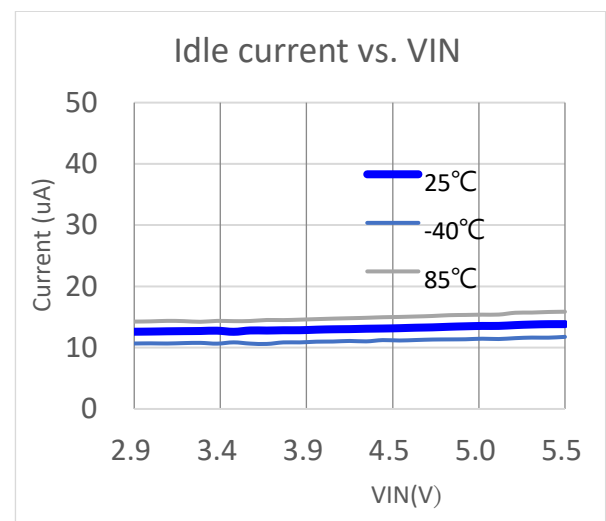
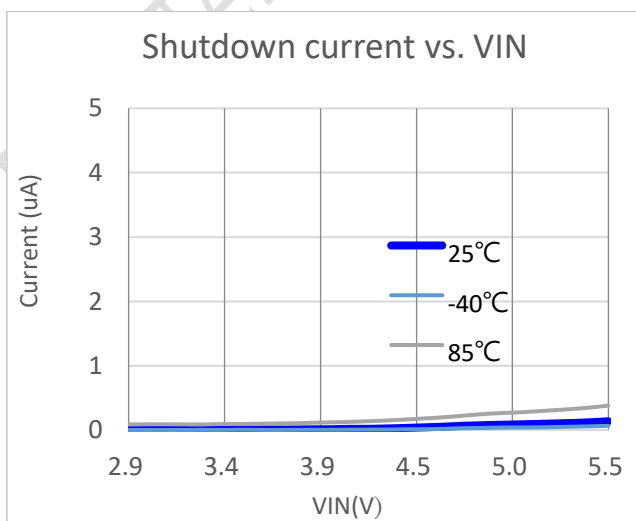
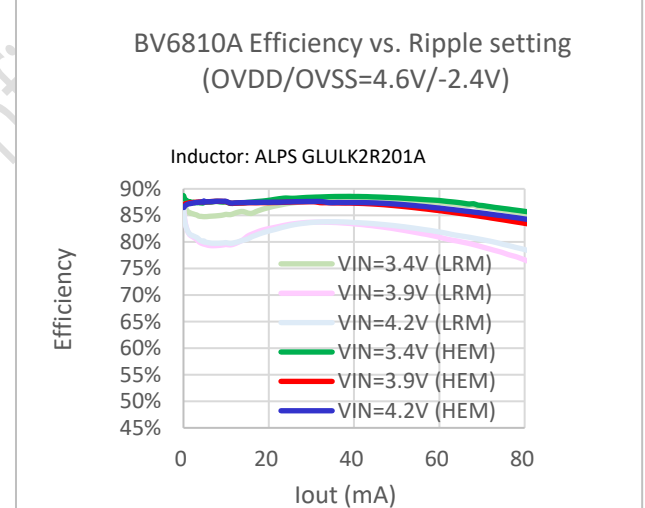
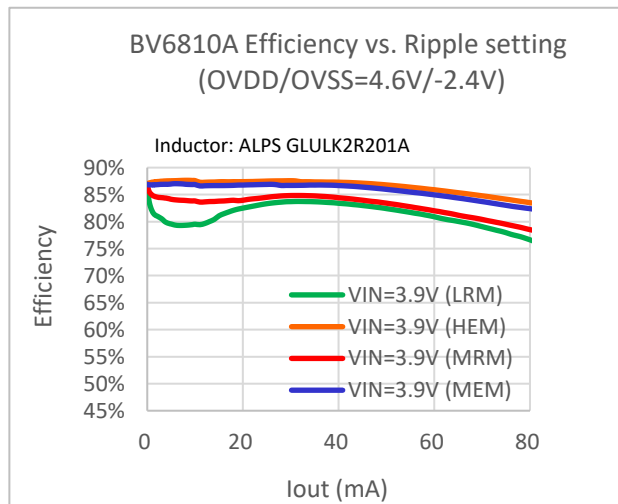
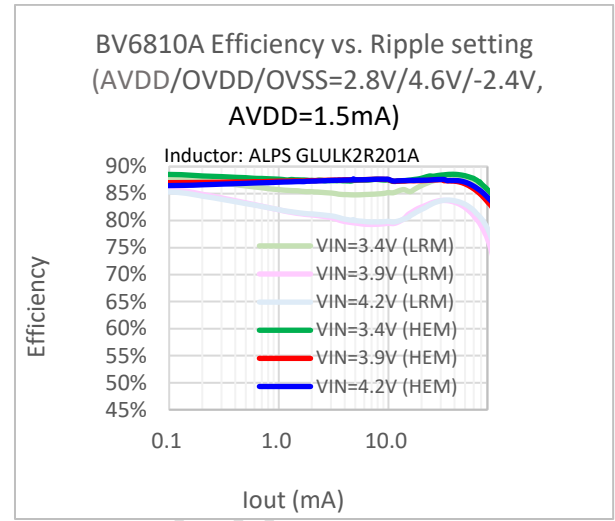
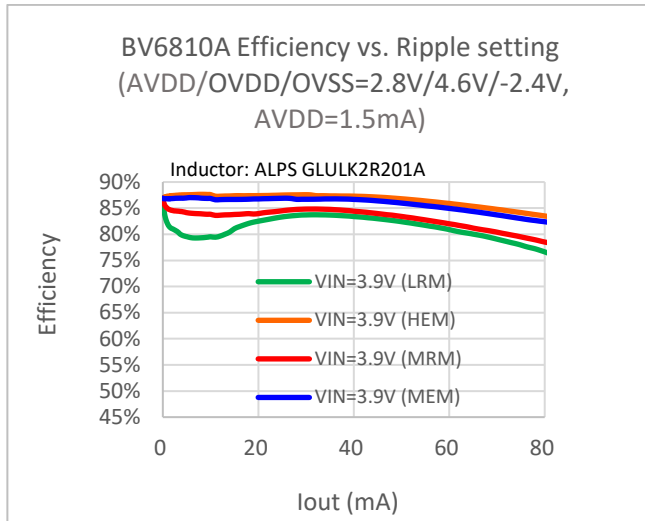
Pulse	AVDD
70	2.8V
71	2.9V
72	3.0V
73	3.1V
74	3.2V
75	3.3V
76	3.4V
77	3.5V
78	3.6V
79	3.7V

Pulse	OVDD
80	2.6V
81	2.7V
82	2.8V
83	2.9V
84	3.0V
85	3.1V
86	3.2V
87	3.3V
88	3.4V
89	3.5V
90	3.6V
91	3.7V
92	3.8V
93	3.9V
94	4.0V
95	4.1V
96	4.2V
97	4.3V
98	4.4V
99	4.5V
100	4.6V
101	4.7V
102	4.8V
103	4.9V
104	5.0V
105	5.1V
106	5.2V
107	5.3V

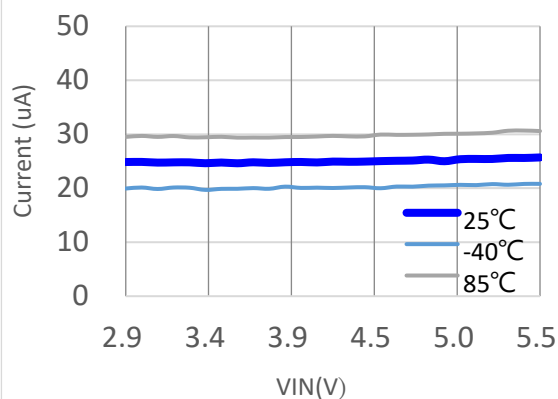
Pulse	OVSS	Pulse	OVSS
20	-4.7V	41	-2.6V
21	-4.6V	42	-2.5V
22	-4.5V	43	-2.4V
23	-4.4V	44	-2.3V
24	-4.3V	45	-2.2V
25	-4.2V	46	-2.1V
26	-4.1V	47	-2.0V
27	-4.0V	48	-1.9V
28	-3.9V	49	-1.8V
29	-3.8V	50	-1.7V
30	-3.7V	51	-1.6V
31	-3.6V	52	-1.5V
32	-3.5V	53	-1.4V
33	-3.4V	54	-1.3V
34	-3.3V	55	-1.2V
35	-3.2V	56	-1.1V
36	-3.1V	57	-1.0V
37	-3.0V	58	-0.9V
38	-2.9V	59	-0.8V
39	-2.8V	60	-0.7V
40	-2.7V	61	-0.6V

14 Operating Curve

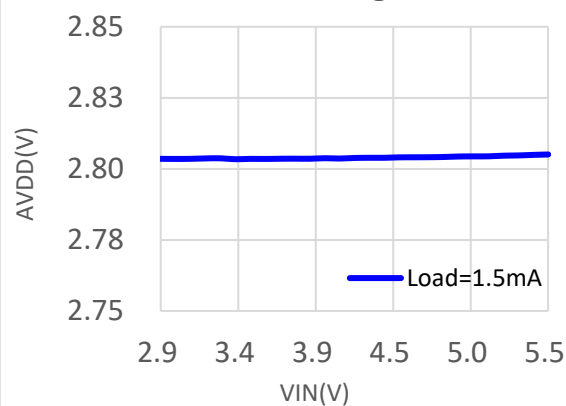
VIN=3.7V, AVDD=2.8V, OVDD=4.6V, OVSS=-2.4V, TA=25°C, unless otherwise specified



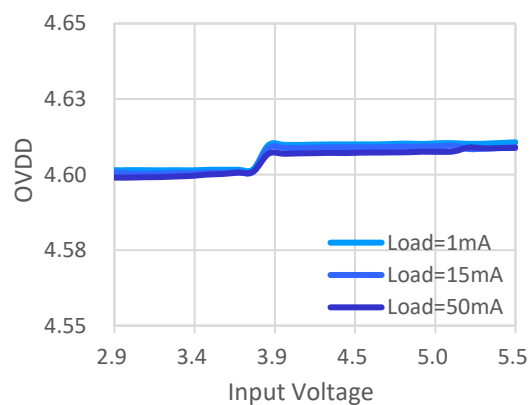
Normal current vs. VIN



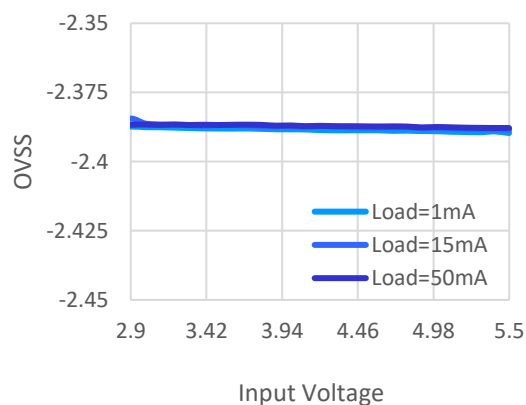
AVDD Line Regulation



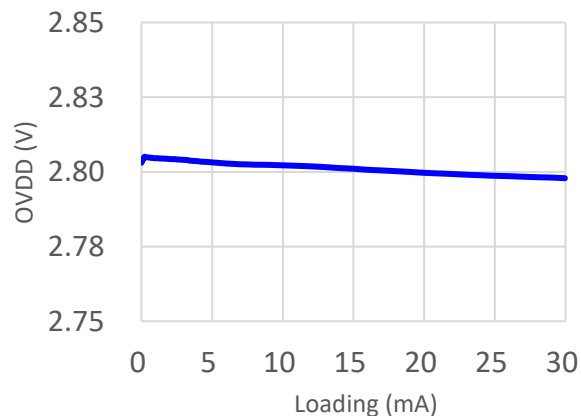
OVDD Line Regulation



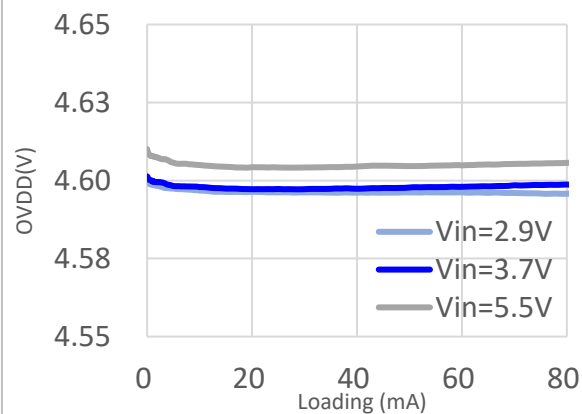
OVSS Line Regulation



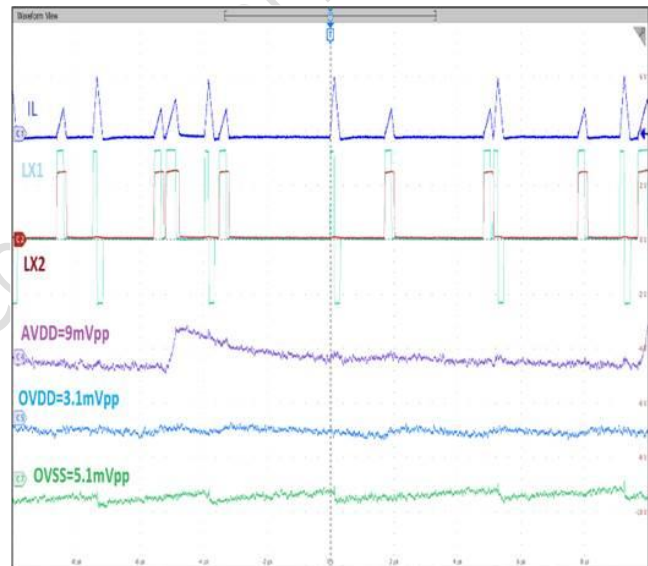
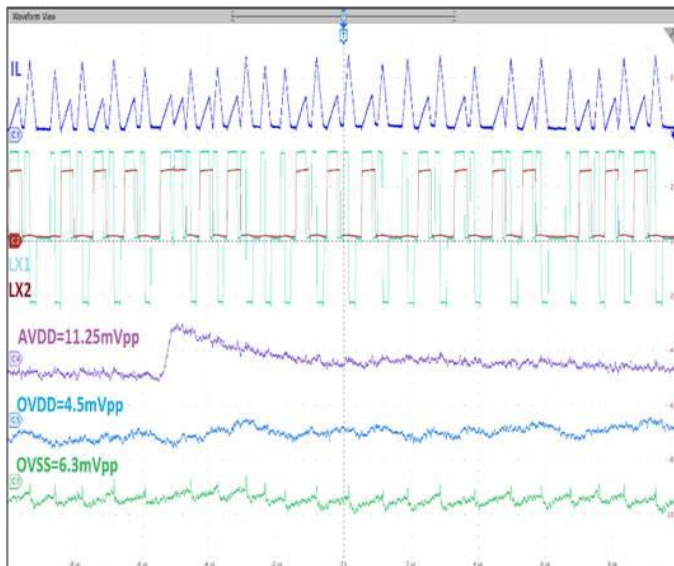
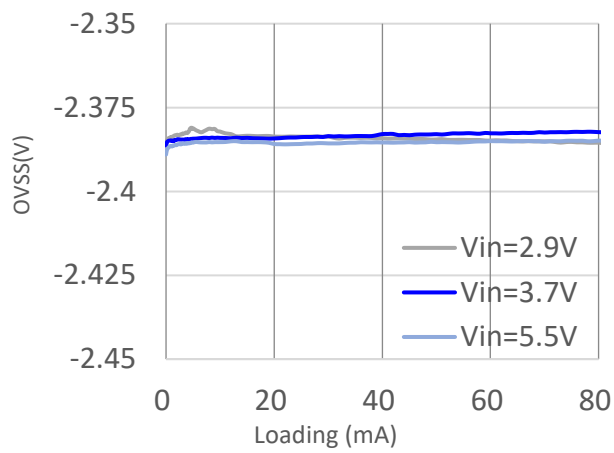
AVDD Load Regulation



OVDD Load Regulation



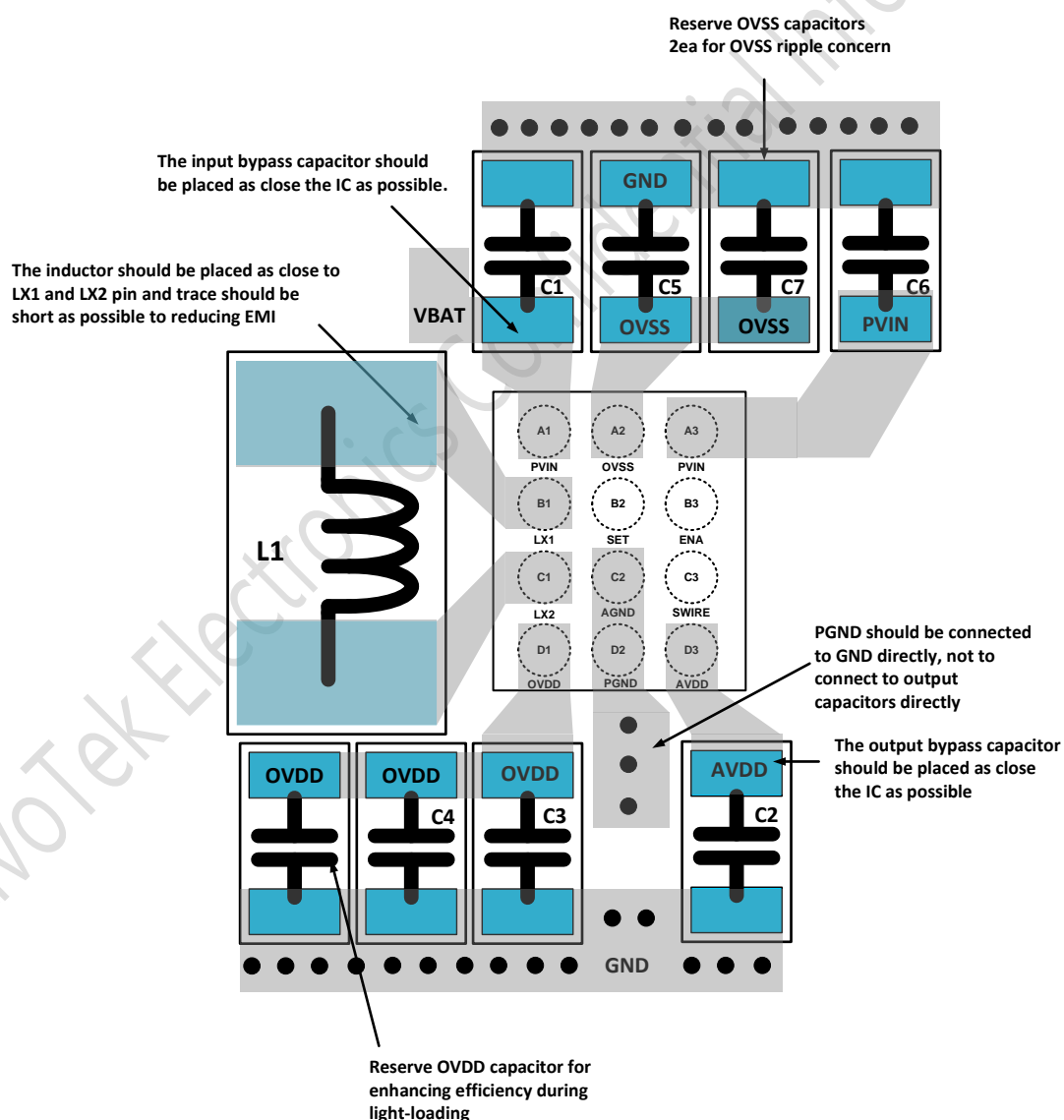
OVSS Load Regulation



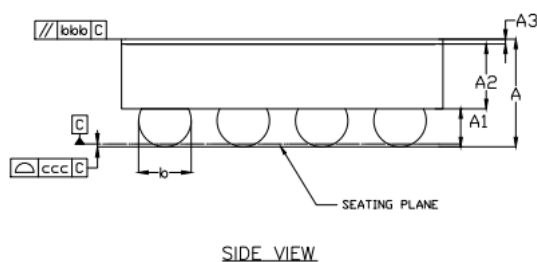
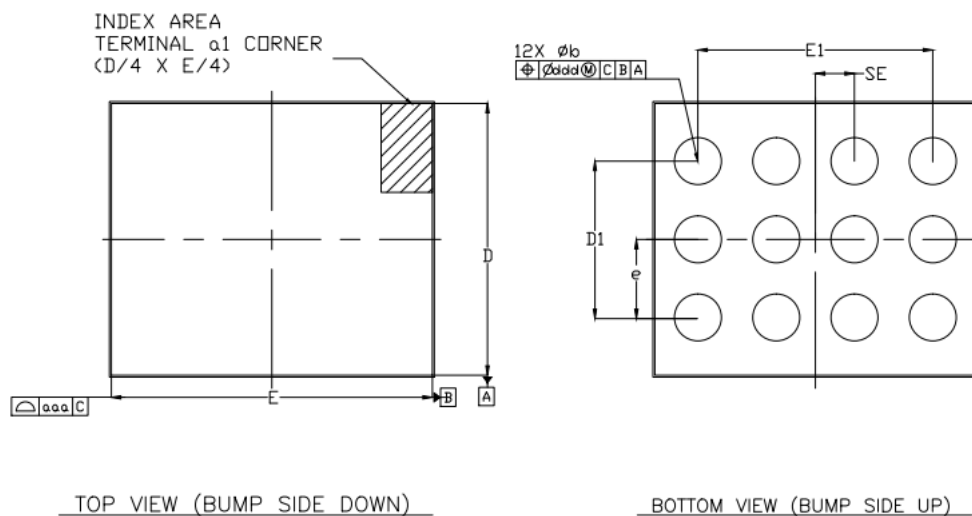
15 Layout Guidelines

For the best performance of the BV6810A, the basic principles listed should be strictly followed.

- Place C1 and C6 as close as possible to the PVIN pins respectively.
- Place C2, C3, C4 and C5 as close as possible to the AVDD, OVDD and OVSS pins respectively.
- Place L1 as close as possible to the LX1 and LX2 pins.
- For good regulation, the power traces should be wide and short especially for the high current output loop.
- Do not connect PGND with output ground directly.
- Reserve OVSS capacitors 2ea for OVSS ripple concern.
- Reserve OVDD capacitor for enhancing efficiency when light-loading
- Bottom layer should have ground plant



16 Outline Dimension



DIMENSIONAL REFERENCES (mm)			
REF.	MIN	NOM	MAX
A	0.502	0.549	0.596
A1	0.175	0.194	0.213
A2	0.305	0.330	0.355
A3	0.022	0.025	0.028
D	1.390		
E	1.640		
b	0.228	0.268	0.308
D1	0.800 BSC		
E1	1.200 BSC		
SD	—		
SE	0.200 BSC		
e	0.400 BSC		
aaa	0.030		
bbb	0.060		
ccc	0.050		
ddd	0.015		

17 Packing Information

Orderable Device	Status	Package Type	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking
BV6810AW	ACTIVE	WLCSP	12	3,000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-1 YEAR	-40 to 85	6810A

- The status is to reflect current situation in marketing.

ACTIVE: The product currently is on sale.

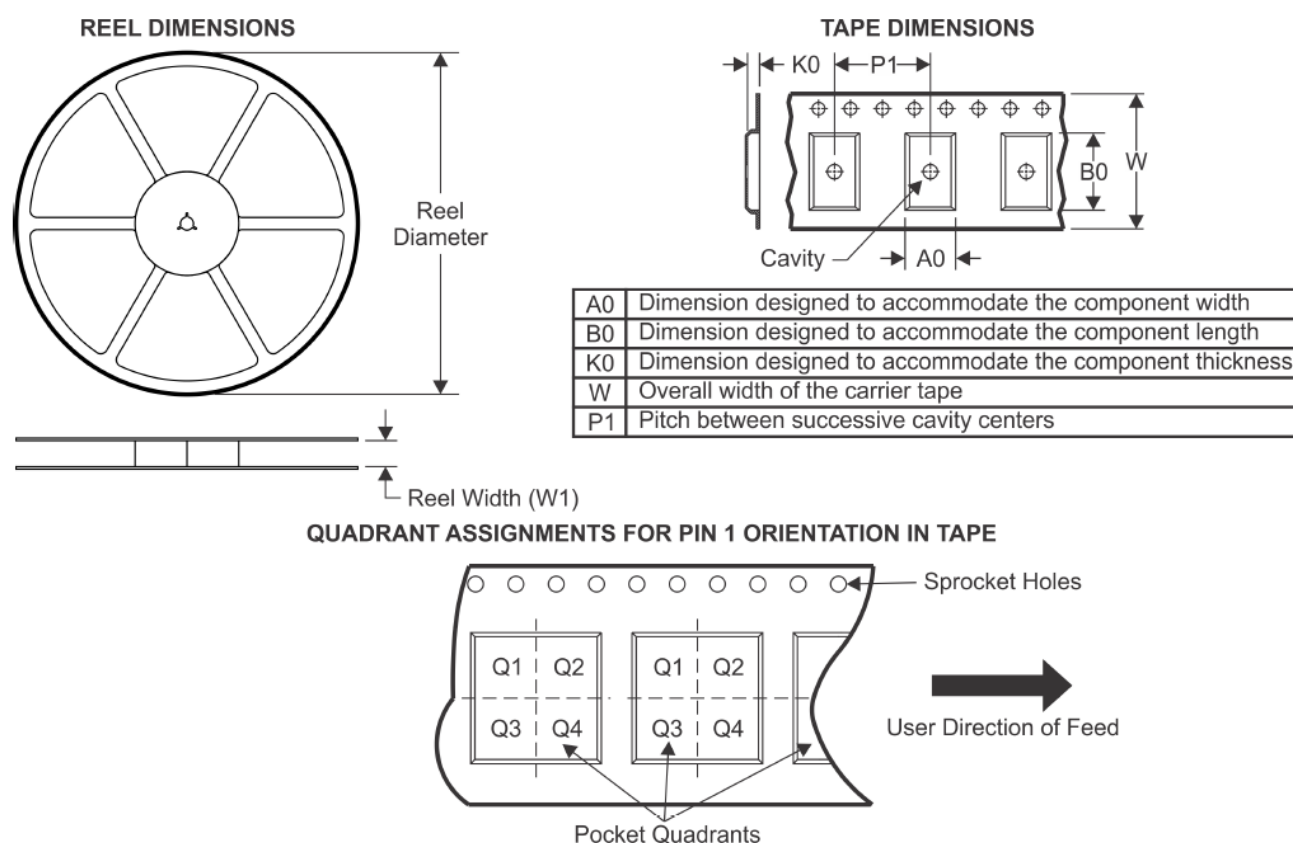
LAST TIME BUY in EOL: Bravotekcorp announced this product will be discontinued. Only last time buy supported within a half of a year.

SAMPLES BY REQUEST: The product is still in developing. Samples may or may not be available.

OBSOLETE: Bravotekcorp has terminated the production of this product.
- Green: Bravotekcorp defines that the product follow JS709B low halogen requirements of $\leq 1,000$ ppm.

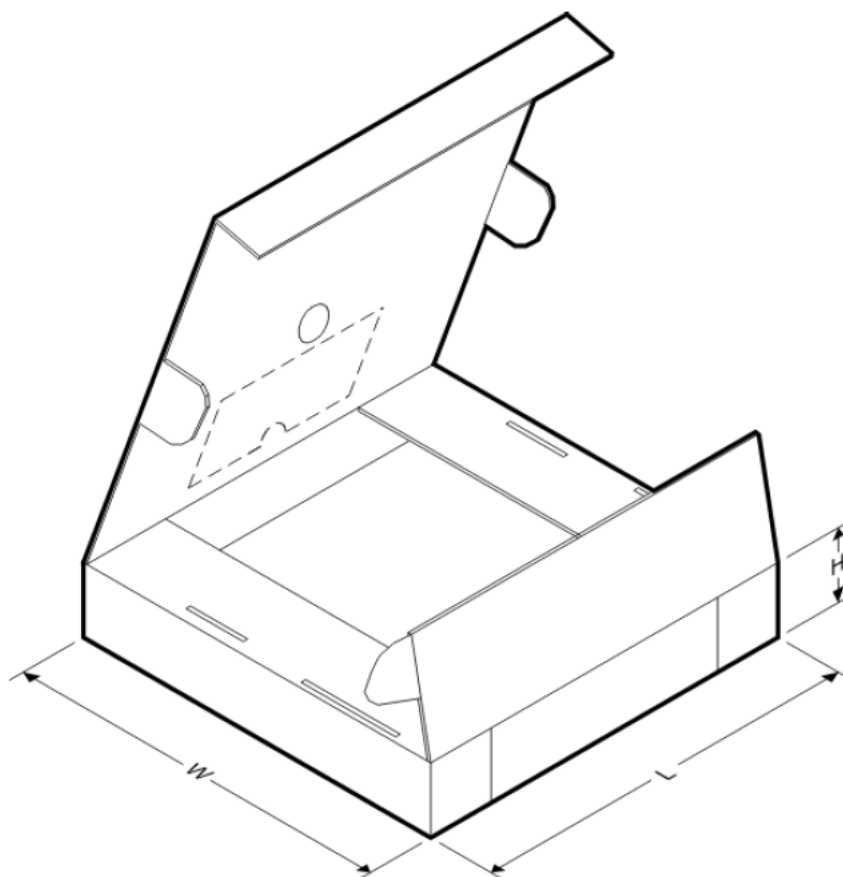
RoHS: Bravotekcorp defines that the product follows current EU RoHS requirements.
- MSL, Peak Temp.: The Moisture Sensitivity Level rating was based on JEDEC industry standard classification, and peak solder temperature.
- Device marking: The device marking of the product will follow Bravotekcorp's marking rule that may contain multiple information for tracing.

18 Tape and Reel Information



Device	Package Type	Pins	SPQ	Reel Diameters (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BV6810AW	WLCSP	12	3000	180	9	1.57+/-0.05	1.81+/-0.05	0.77+/-0.05	4	8	Q1

19 Tape and Reel Box Dimension



Device	Package Type	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BV6810AW	WLCSP	12	3000	183+/-5	183+/-5	85+/-5

20 VERSION HISTORY

Version #	Implemented By	Revision Date	Approved By	Approval Date	Reason
0.1	Elvie	03.15.2024			Initial Design Definition
0.2	Elvie	04.02.2024			Add . IAVDD_LIMIT 20(Typ) Modify . Iocp 1.05→1.15(Max) . LX Slew rate Control -Pulse 3 →Pulse 5 (Default)
0.3	Elvie	04.15.2024			Change capacitor Component supplier . C1, C2, C5, C7, C3- C4CL05A106MP5NRNC(10uF/ 10V)→GRM155R60J106ME15 D (10uF/6.3V) . C6- CL05A105KP5NFN(1uF/10V) →GRM153R60J105ME15D(1u F/6.3V) . C3, C4- GRM158R61A226ME15D(22u F/10V)→GRM158R60J226ME 01D(22uF/6.3V)
0.4	Elvie	04.23.2024			Add a Description for the Note in Chapter 5 - Application Circuit
0.5	Elvie	05.11.2024			. Change PIN- AVIN to PVIN. . Change in part number and specifications of C6 GRM153R60J105ME15D→ GRM033R60J104KE19D

Template Version: 09/09, 2019